

INFORMATION DISCLOSURE CITATION (Use several sheets if necessary)				Docket Number (Optional) END920030032US1 (16704)		Application Number 10/665,993			
				Applicant(s) Raminderpal Singh, et al.		Filing Date Herewith		Group Art Unit 2826	
				U.S. PATENT DOCUMENTS					
*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE		
VANJ		5,922,650	7/13/99	Ye					
↓		6,205,013B1	3/20/01	Gong et al.					
↓		2001/0040490A1	11/15/01	Tanaka					
↓		2002/0102835A1	8/1/02	Stucchi et al.					
FOREIGN PATENT DOCUMENTS									
REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION			
						YES	NO		
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)									
VANJ		Silicon RF Technology-The Two Generic Approaches by Joachim N. Burghartz							
EXAMINER <i>Victor A. Mandelker Jr.</i>				DATE CONSIDERED <i>4-18-05</i>					
EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.									